

SN74AUCH32374

32-BIT EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH 3-STATE OUTPUTS

SCES476 – AUGUST 2003

- Member of the Texas Instruments Widebus+™ Family
- Optimized for 1.8-V Operation and is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode Operation
- Sub 1-V Operable
- Max t_{pd} of 2.8 ns at 1.8 V
- Low Power Consumption, 40-μA Max I_{CC}
- ±8-mA Output Drive at 1.8 V
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

description/ordering information

This 32-bit edge-triggered D-type flip-flop is operational at 0.8-V to 2.7-V V_{CC}, but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUCH32374 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. It can be used as four 8-bit flip-flops, two 16-bit flip-flops, or one 32-bit flip-flop. On the positive transition of the clock (CLK) input, the Q outputs of the flip-flop take on the logic levels set up at the data (D) inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

\overline{OE} does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

| T _A | PACKAGE† | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|------------------------------|-----------------------|------------------|
| –40°C to 85°C | LFBGA – GKE Tape and reel | SN74AUCH32374GKER | MK374 |

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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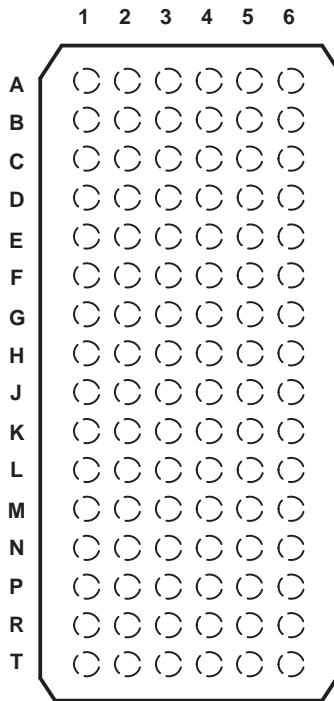
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SCES476 – AUGUST 2003

GKE PACKAGE
(TOP VIEW)



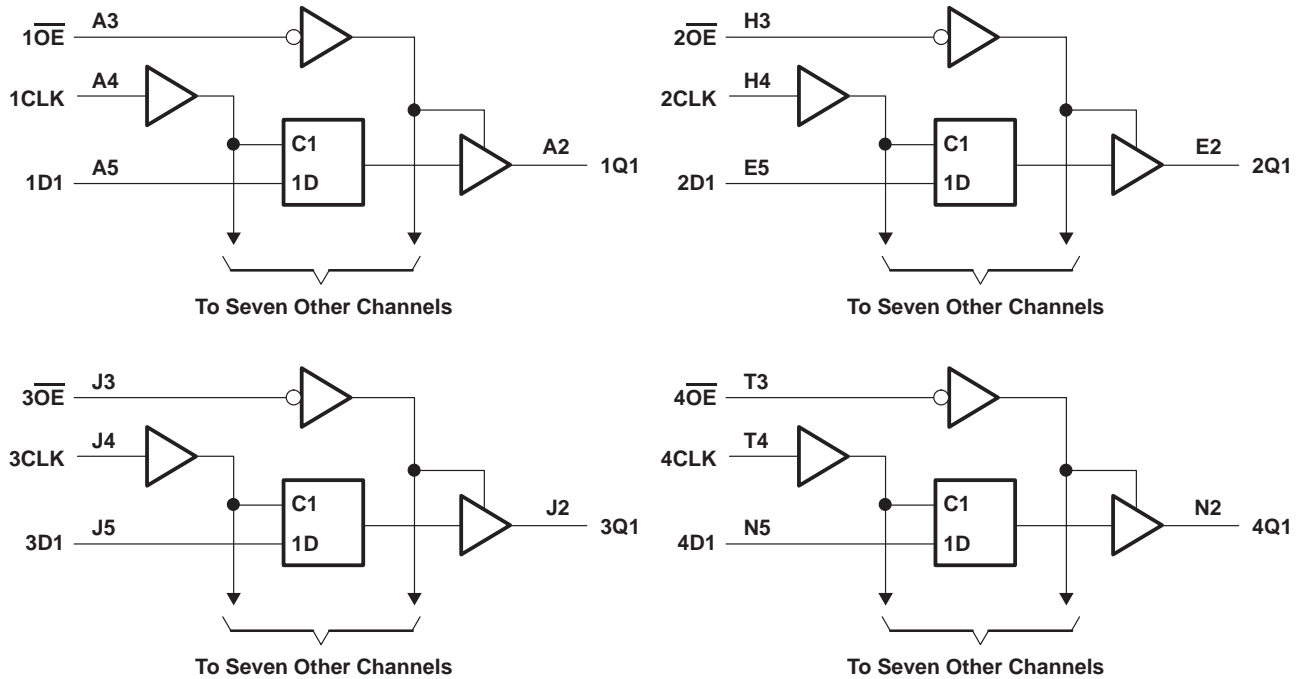
terminal assignments

| | 1 | 2 | 3 | 4 | 5 | 6 |
|---|-----|-----|------------------|-----------------|-----|-----|
| A | 1Q2 | 1Q1 | $\overline{1OE}$ | 1CLK | 1D1 | 1D2 |
| B | 1Q4 | 1Q3 | GND | GND | 1D3 | 1D4 |
| C | 1Q6 | 1Q5 | V _{CC} | V _{CC} | 1D5 | 1D6 |
| D | 1Q8 | 1Q7 | GND | GND | 1D7 | 1D8 |
| E | 2Q2 | 2Q1 | GND | GND | 2D1 | 2D2 |
| F | 2Q4 | 2Q3 | V _{CC} | V _{CC} | 2D3 | 2D4 |
| G | 2Q6 | 2Q5 | GND | GND | 2D5 | 2D6 |
| H | 2Q7 | 2Q8 | $\overline{2OE}$ | 2CLK | 2D8 | 2D7 |
| J | 3Q2 | 3Q1 | $\overline{3OE}$ | 3CLK | 3D1 | 3D2 |
| K | 3Q4 | 3Q3 | GND | GND | 3D3 | 3D4 |
| L | 3Q6 | 3Q5 | V _{CC} | V _{CC} | 3D5 | 3D6 |
| M | 3Q8 | 3Q7 | GND | GND | 3D7 | 3D8 |
| N | 4Q2 | 4Q1 | GND | GND | 4D1 | 4D2 |
| P | 4Q4 | 4Q3 | V _{CC} | V _{CC} | 4D3 | 4D4 |
| R | 4Q6 | 4Q5 | GND | GND | 4D5 | 4D6 |
| T | 4Q7 | 4Q8 | $\overline{4OE}$ | 4CLK | 4D8 | 4D7 |

FUNCTION TABLE
(each flip-flop)

| INPUTS | | | OUTPUT |
|-----------------|--------|---|----------------|
| \overline{OE} | CLK | D | Q |
| L | ↑ | H | H |
| L | ↑ | L | L |
| L | H or L | X | Q ₀ |
| H | X | X | Z |

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| | |
|---|----------------------------|
| Supply voltage range, V_{CC} | -0.5 V to 3.6 V |
| Input voltage range, V_I (see Note 1) | -0.5 V to 3.6 V |
| Voltage range applied to any output in the high-impedance or power-off state, V_O (see Note 1) | -0.5 V to 3.6 V |
| Output voltage range, V_O (see Note 1) | -0.5 V to $V_{CC} + 0.5$ V |
| Input clamp current, I_{IK} ($V_I < 0$) | -50 mA |
| Output clamp current, I_{OK} ($V_O < 0$) | -50 mA |
| Continuous output current, I_O | ± 20 mA |
| Continuous current through V_{CC} or GND | ± 100 mA |
| Package thermal impedance, θ_{JA} (see Note 2) | 40°C/W |
| Storage temperature range, T_{stg} | -65°C to 150°C |

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
 2. The package thermal impedance is calculated in accordance with JESD 51-7.

SN74AUCH32374
32-BIT EDGE-TRIGGERED D-TYPE FLIP-FLOP
WITH 3-STATE OUTPUTS

SCES476 – AUGUST 2003

recommended operating conditions (see Note 3)

| | | MIN | MAX | UNIT | |
|-----------------|------------------------------------|-----------------------------------|------------------------|-----------------|---|
| V _{CC} | Supply voltage | 0.8 | 2.7 | V | |
| V _{IH} | High-level input voltage | V _{CC} = 0.8 V | V _{CC} | V | |
| | | V _{CC} = 1.1 V to 1.95 V | 0.65 × V _{CC} | | |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | | |
| V _{IL} | Low-level input voltage | V _{CC} = 0.8 V | 0 | V | |
| | | V _{CC} = 1.1 V to 1.95 V | 0.35 × V _{CC} | | |
| | | V _{CC} = 2.3 V to 2.7 V | 0.7 | | |
| V _I | Input voltage | 0 | 3.6 | V | |
| V _O | Output voltage | Active state | 0 | V _{CC} | V |
| | | 3-state | 0 | 3.6 | V |
| I _{OH} | High-level output current | V _{CC} = 0.8 V | -0.7 | mA | |
| | | V _{CC} = 1.1 V | -3 | | |
| | | V _{CC} = 1.4 V | -5 | | |
| | | V _{CC} = 1.65 V | -8 | | |
| | | V _{CC} = 2.3 V | -9 | | |
| I _{OL} | Low-level output current | V _{CC} = 0.8 V | 0.7 | mA | |
| | | V _{CC} = 1.1 V | 3 | | |
| | | V _{CC} = 1.4 V | 5 | | |
| | | V _{CC} = 1.65 V | 8 | | |
| | | V _{CC} = 2.3 V | 9 | | |
| Δt/Δv | Input transition rise or fall rate | | 20 | ns/V | |
| T _A | Operating free-air temperature | -40 | 85 | °C | |

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



SN74AUCH32374
32-BIT EDGE-TRIGGERED D-TYPE FLIP-FLOP
WITH 3-STATE OUTPUTS

SCES476 – AUGUST 2003

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | V _{CC} | MIN | TYP† | MAX | UNIT |
|---------------------|---------------------------------------|---|-----------------|----------------------|------|------|------|
| V _{OH} | | I _{OH} = -100 μA | 0.8 V to 2.7 V | V _{CC} -0.1 | | | V |
| | | I _{OH} = -0.7 mA | 0.8 V | 0.55 | | | |
| | | I _{OH} = -3 mA | 1.1 V | 0.8 | | | |
| | | I _{OH} = -5 mA | 1.4 V | 1 | | | |
| | | I _{OH} = -8 mA | 1.65 V | 1.2 | | | |
| | | I _{OH} = -9 mA | 2.3 V | 1.8 | | | |
| V _{OL} | | I _{OL} = 100 μA | 0.8 V to 2.7 V | | | 0.2 | V |
| | | I _{OL} = 0.7 mA | 0.8 V | 0.25 | | | |
| | | I _{OL} = 3 mA | 1.1 V | | | 0.3 | |
| | | I _{OL} = 5 mA | 1.4 V | | | 0.4 | |
| | | I _{OL} = 8 mA | 1.65 V | | | 0.45 | |
| | | I _{OL} = 9 mA | 2.3 V | | | 0.6 | |
| I _I | All inputs | V _I = V _{CC} or GND | 0 to 2.7 V | | | ±5 | μA |
| I _{BHL} ‡ | | V _I = 0.35 V | 1.1 V | 10 | | | μA |
| | | V _I = 0.47 V | 1.4 V | 15 | | | |
| | | V _I = 0.57 V | 1.65 V | 20 | | | |
| | | V _I = 0.7 V | 2.3 V | 40 | | | |
| I _{BHH} § | | V _I = 0.8 V | 1.1 V | -5 | | | μA |
| | | V _I = 0.9 V | 1.4 V | -15 | | | |
| | | V _I = 1.07 V | 1.65 V | -20 | | | |
| | | V _I = 1.7 V | 2.3 V | -40 | | | |
| I _{BHLO} ¶ | V _I = 0 to V _{CC} | | 1.3 V | 75 | | | μA |
| | | | 1.6 V | 125 | | | |
| | | | 1.95 V | 175 | | | |
| | | | 2.7 V | 275 | | | |
| I _{BHHO} # | V _I = 0 to V _{CC} | | 1.3 V | -75 | | | μA |
| | | | 1.6 V | -125 | | | |
| | | | 1.95 V | -175 | | | |
| | | | 2.7 V | -275 | | | |
| I _{off} | | V _I or V _O = 2.7 V | 0 | | | ±10 | μA |
| I _{OZ} | | V _O = V _{CC} or GND | 2.7 V | | | ±10 | μA |
| I _{CC} | | V _I = V _{CC} or GND, I _O = 0 | 0.8 V to 2.7 V | | | 40 | μA |
| C _i | | V _I = V _{CC} or GND | 2.5 V | 3 | | | pF |
| C _o | | V _O = V _{CC} or GND | 2.5 V | 5 | | | pF |

† All typical values are at T_A = 25°C.

‡ The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

§ The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

¶ An external driver must source at least I_{BHLO} to switch this node from low to high.

An external driver must sink at least I_{BHHO} to switch this node from high to low.



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SCES476 – AUGUST 2003

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

| | | V _{CC} = 0.8 V | V _{CC} = 1.2 V ± 0.1 V | | V _{CC} = 1.5 V ± 0.1 V | | V _{CC} = 1.8 V ± 0.15 V | | V _{CC} = 2.5 V ± 0.2 V | | UNIT |
|--------------------|---------------------------------|-------------------------|------------------------------------|-----|------------------------------------|-----|-------------------------------------|-----|------------------------------------|-----|------|
| | | TYP | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| f _{clock} | Clock frequency | 85 | 250 | | 250 | | 250 | | 250 | | MHz |
| t _w | Pulse duration, CLK high or low | 5.9 | 1.9 | | 1.9 | | 1.9 | | 1.9 | | ns |
| t _{su} | Setup time, data before CLK↑ | 1.4 | 1.2 | | 0.7 | | 0.6 | | 0.6 | | ns |
| t _h | Hold time, data after CLK↑ | 0.1 | 0.4 | | 0.4 | | 0.4 | | 0.4 | | ns |

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = 0.8 V | V _{CC} = 1.2 V ± 0.1 V | | V _{CC} = 1.5 V ± 0.1 V | | V _{CC} = 1.8 V ± 0.15 V | | | V _{CC} = 2.5 V ± 0.2 V | | UNIT |
|------------------|-----------------|----------------|-------------------------|------------------------------------|-----|------------------------------------|-----|-------------------------------------|-----|-----|------------------------------------|-----|------|
| | | | TYP | MIN | MAX | MIN | MAX | MIN | TYP | MAX | MIN | MAX | |
| f _{max} | | | 85 | 250 | | 250 | | 250 | | | 250 | | MHz |
| t _{pd} | CLK | Q | 7.3 | 1 | 4.5 | 0.8 | 2.9 | 0.7 | 1.5 | 2.8 | 0.7 | 2.2 | ns |
| t _{en} | \overline{OE} | Q | 7 | 1.2 | 5.3 | 0.8 | 3.6 | 0.8 | 1.5 | 2.9 | 0.7 | 2.2 | ns |
| t _{dis} | \overline{OE} | Q | 8.2 | 2 | 7.1 | 1 | 4.8 | 1.4 | 2.7 | 4.5 | 0.5 | 2.2 | ns |

operating characteristics, T_A = 25°C†

| PARAMETER | | | TEST CONDITIONS | V _{CC} = 0.8 V | V _{CC} = 1.2 V | V _{CC} = 1.5 V | V _{CC} = 1.8 V | V _{CC} = 2.5 V | UNIT |
|------------------------------------|-------------------------------|--|--|-------------------------|-------------------------|-------------------------|-------------------------|-------------------------|------|
| | | | | TYP | TYP | TYP | TYP | TYP | |
| C _{pd} ‡ (each output) | Power dissipation capacitance | Outputs enabled, 1 output switching | 1 f _{data} = 5 MHz 1 f _{clk} = 10 MHz 1 f _{out} = 5 MHz \overline{OE} = GND C _L = 0 pF | 24 | 24 | 24.1 | 26.2 | 31.2 | pF |
| C _{pd} (Z) | Power dissipation capacitance | Outputs disabled, 1 clock and 1 data switching | 1 f _{data} = 5 MHz 1 f _{clk} = 10 MHz f _{out} = not switching \overline{OE} = V _{CC} C _L = 0 pF | 7.5 | 7.5 | 8 | 9.4 | 13.2 | pF |
| C _{pd} § (each clock) | Power dissipation capacitance | Outputs disabled, clock only switching | 1 f _{data} = 0 MHz 1 f _{clk} = 10 MHz f _{out} = not switching \overline{OE} = V _{CC} C _L = 0 pF | 13.8 | 13.8 | 14 | 14.7 | 17.5 | pF |

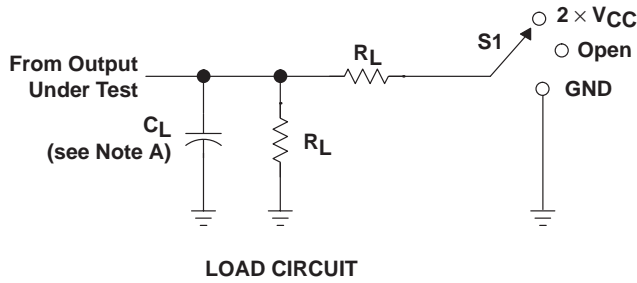
† Total device C_{pd} for multiple (n) outputs switching and (y) clocks inputs switching = {n * C_{pd} (each output)} + {y * C_{pd} (each clock)}.

‡ C_{pd} (each output) is the C_{pd} for each data bit (input and output circuitry) as it operates at 5 MHz (Note: the clock is operating at 10 MHz in this test, but its I_{CC} component has been subtracted out).

§ C_{pd} (each clock) is the C_{pd} for the clock circuitry only as it operates at 10 MHz.

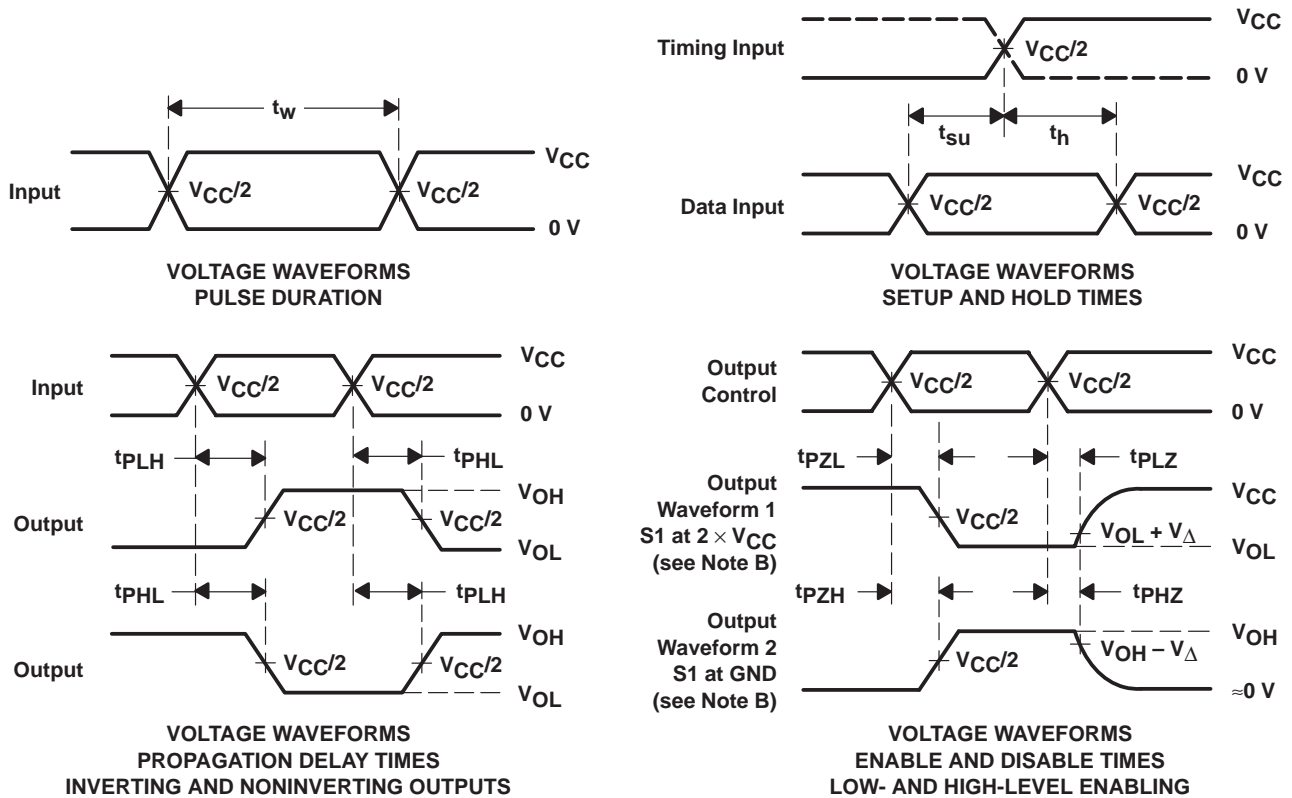


PARAMETER MEASUREMENT INFORMATION



| TEST | S1 |
|-------------------|-------------------|
| t_{PLH}/t_{PHL} | Open |
| t_{PLZ}/t_{PZL} | $2 \times V_{CC}$ |
| t_{PHZ}/t_{PZH} | GND |

| V_{CC} | C_L | R_L | V_{Δ} |
|------------------------------------|-------|--------------|--------------|
| 0.8 V | 15 pF | 2 k Ω | 0.1 V |
| $1.2 \text{ V} \pm 0.1 \text{ V}$ | 15 pF | 2 k Ω | 0.1 V |
| $1.5 \text{ V} \pm 0.1 \text{ V}$ | 15 pF | 2 k Ω | 0.1 V |
| $1.8 \text{ V} \pm 0.15 \text{ V}$ | 30 pF | 1 k Ω | 0.15 V |
| $2.5 \text{ V} \pm 0.2 \text{ V}$ | 30 pF | 500 Ω | 0.15 V |



- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50 \Omega$, slew rate ≥ 1 V/ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|-------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|
| SN74AUCH32374GKER | ACTIVE | LFBGA | GKE | 96 | 1000 | None | SNPB | Level-3-220C-168 HR |
| SN74AUCH32374ZKER | ACTIVE | LFBGA | ZKE | 96 | 1000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-3-250C-168 HR |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - May not be currently available - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

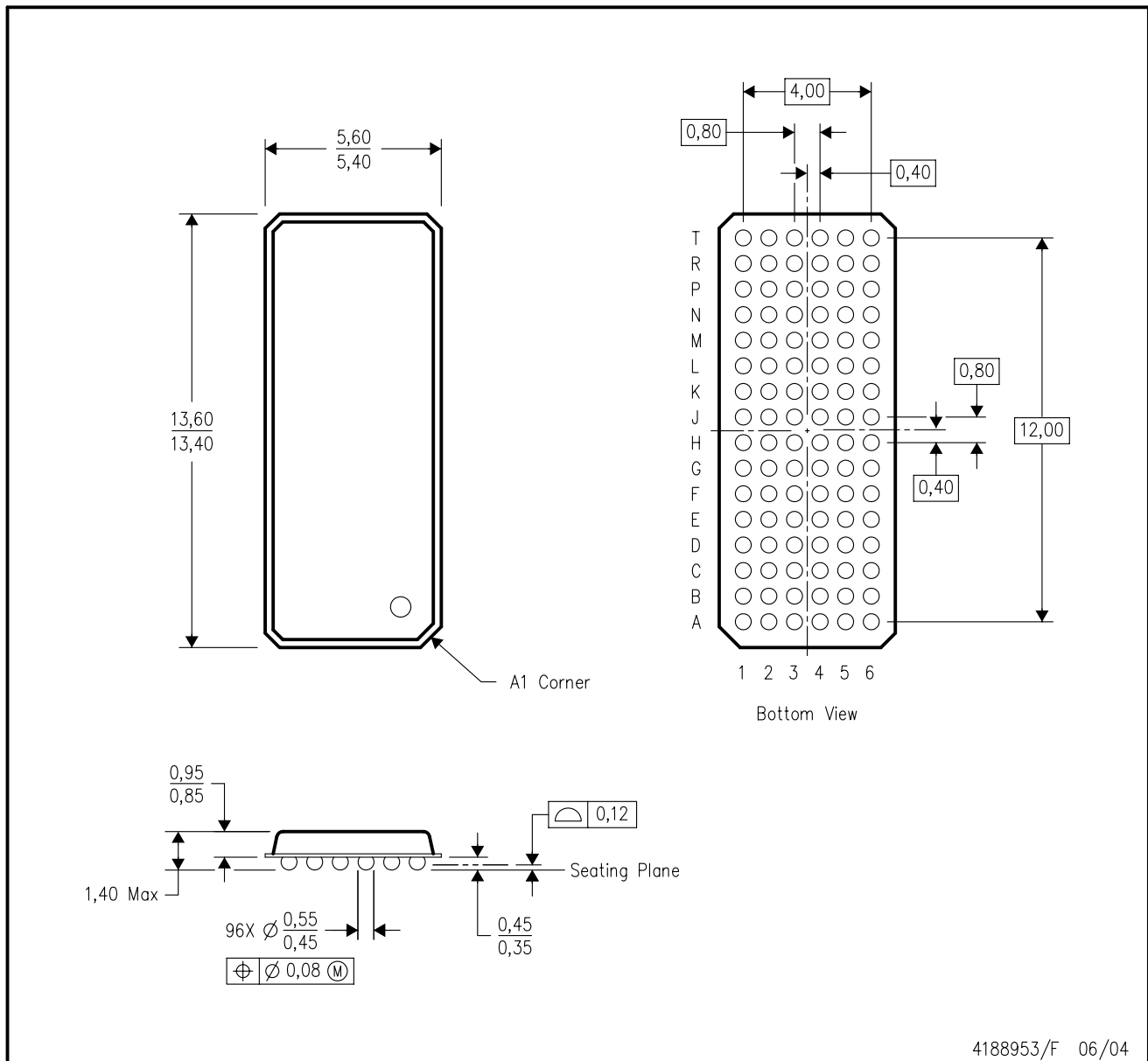
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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GKE (R-PBGA-N96)

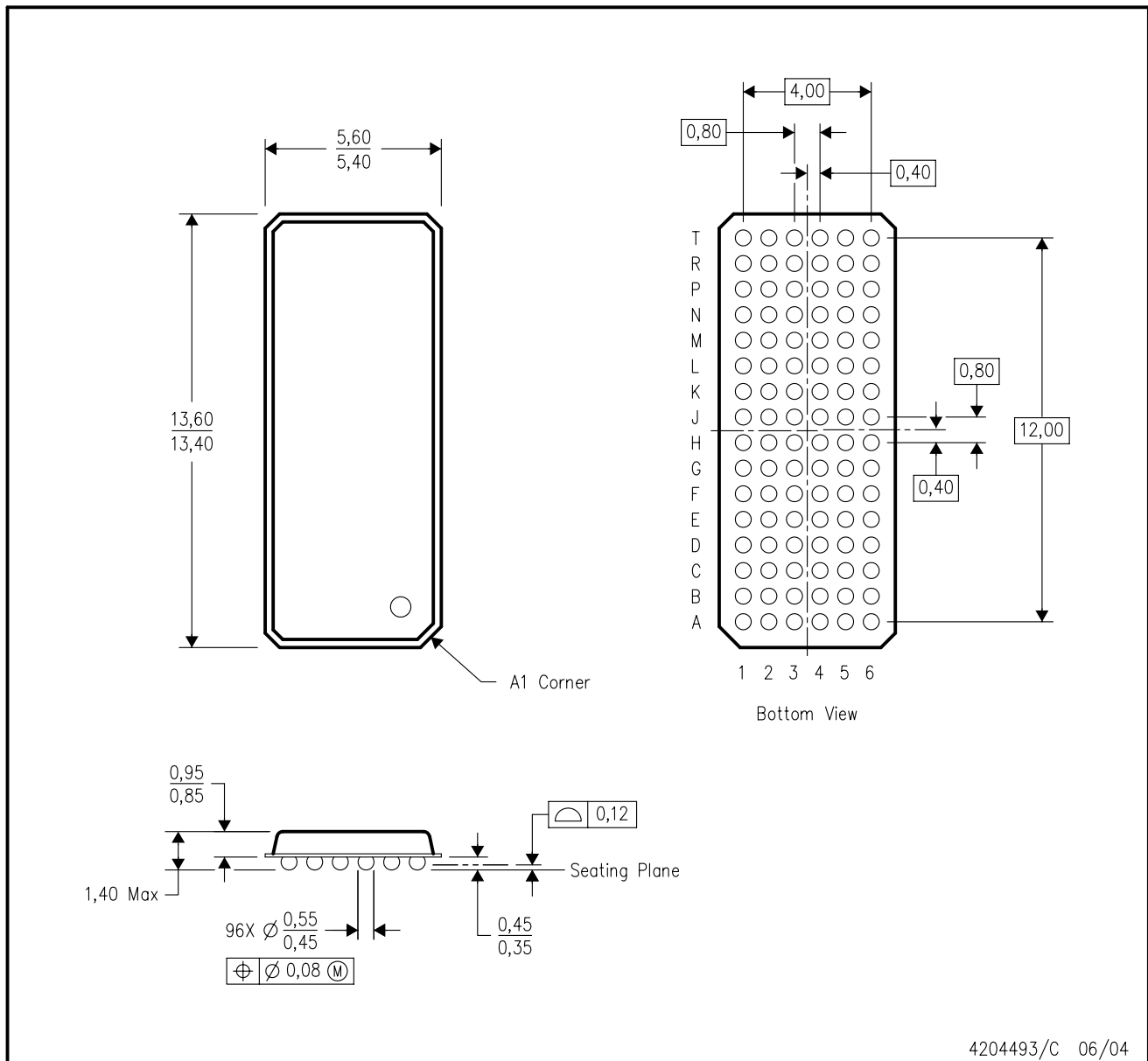
PLASTIC BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MO-205 variation CC.
 - D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.

ZKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MO-205 variation CC.
 - D. This package is lead-free. Refer to the 96 GKE package (drawing 4188953) for tin-lead (SnPb).

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